Single Supply Quad Comparators

These comparators are designed for use in level detection, low-level sensing and memory applications in consumer, automotive, and industrial electronic applications.

Features

- Single or Split Supply Operation
- Low Input Bias Current: 25 nA (Typ)
- Low Input Offset Current: ±5.0 nA (Typ)
- Low Input Offset Voltage
- Input Common Mode Voltage Range to GND
- Low Output Saturation Voltage: 130 mV (Typ) @ 4.0 mA
- TTL and CMOS Compatible
- ESD Clamps on the Inputs Increase Reliability without Affecting Device Operation
- NCV Prefix for Automotive and Other Applications Requiring Site and Control Changes
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

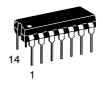


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SOIC-14 D SUFFIX CASE 751A

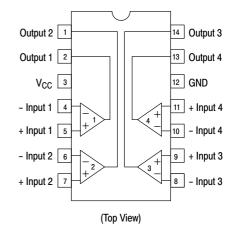


PDIP-14 N, P SUFFIX CASE 646



TSSOP-14 DTB SUFFIX CASE 948G

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

DEVICE MARKING INFORMATION

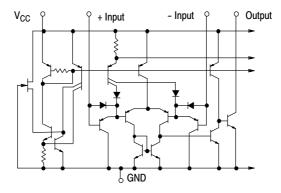
See general marking information in the device marking section on page 8 of this data sheet.

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Power Supply Voltage	LM239/LM339/LM2901, V MC3302	V _{CC}	+36 or ±18 +30 or ±15	Vdc
Input Differential Voltage Range	LM239/LM339/LM2901, V MC3302	V _{IDR}	36 30	Vdc
Input Common Mode Voltage Range		V _{ICMR}	−0.3 to V _{CC}	Vdc
Output Short Circuit to Ground (Note 1)		I _{SC}	Continuous	
Power Dissipation @ T _A = 25°C Plastic Package Derate above 25°C		P _D	1.0 8.0	W mW/°C
Junction Temperature		TJ	150	°C
Operating Ambient Temperature Range	LM239 MC3302 LM2901 LM2901V, NCV2901 LM339	T _A	-25 to +85 -40 to +85 -40 to +105 -40 to +125 0 to +70	°C
Storage Temperature Range		T _{stg}	-65 to +150	°C
ESD Protection at any Pin (Note 2) Human Body Model Machine Model		V _{ESD}	1500 200	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

^{2.} V_{ESD} rating for NCV/SC devices is: Human Body Model – 2000 V; Machine Model – 200 V.



NOTE: Diagram shown is for 1 comparator.

Figure 1. Circuit Schematic

The maximum output current may be as high as 20 mA, independent of the magnitude of V_{CC}. Output short circuits to V_{CC} can cause excessive heating and eventual destruction.

ELECTRICAL CHARACTERISTICS (V_{CC} = +5.0 Vdc, T_A = +25°C, unless otherwise noted)

ELECTRICAL CHARACTERISTICS			.M239/33		LM2901/2901V/ NCV2901			MC3302	!		
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage (Note 4)	V _{IO}	-	±2.0	±5.0	-	±2.0	±7.0	_	±3.0	±20	mVdc
Input Bias Current (Notes 4, 5)	I _{IB}	-	25	250	-	25	250	_	25	500	nA
(Output in Analog Range)											
Input Offset Current (Note 4)	I _{IO}	-	±5.0	±50	-	±5.0	±50	_	±3.0	±100	nA
Input Common Mode Voltage Range	V _{ICMR}	0	-	V _{CC} -1.5	0	-	V _{CC} -1.5	0	-	V _{CC} -1.5	V
Supply Current	I _{CC}										mA
R _L = ∞ (For All Comparators)		-	0.8	2.0	-	0.8	2.0	_	0.8	2.0	
$R_L = \infty$, $V_{CC} = 30 \text{ Vdc}$		-	1.0	2.5	-	1.0	2.5	_	1.0	2.5	
Voltage Gain	A _{VOL}	50	200	-	25	100	-	25	100	-	V/mV
$R_L \ge 15 \text{ k}\Omega$, V_{CC} = 15 Vdc											
Large Signal Response Time	-	-	300	-	-	300	-	_	300	-	ns
$V_I = TTL$ Logic Swing,											
V_{ref} = 1.4 Vdc, V_{RL} = 5.0 Vdc,											
$R_L = 5.1 \text{ k}\Omega$											
Response Time (Note 6)	-	-	1.3	-	-	1.3	-	_	1.3	-	μs
V_{RL} = 5.0 Vdc, R_L = 5.1 k Ω											
Output Sink Current	I _{Sink}	6.0	16	-	6.0	16	-	6.0	16	-	mA
V_{I} (-) \geq +1.0 Vdc, V_{I} (+) = 0, $V_{O} \leq$ 1.5 Vdc											
Saturation Voltage	V _{sat}	-	130	400	-	130	400	_	130	500	mV
$V_I(-) \ge +1.0 \text{ Vdc}, V_I(+) = 0,$ $I_{sink} \le 4.0 \text{ mA}$											
Output Leakage Current	I _{OL}	-	0.1	_	-	0.1	_	_	0.1	-	nA
$\begin{split} &V_I(+) \geq +1.0 \text{ Vdc}, \ V_I(-) = 0, \\ &V_O = +5.0 \text{ Vdc} \end{split}$											

^{3. (}LM239) T_{low} = -25°C, T_{high} = +85° (LM339) T_{low} = 0°C, T_{high} = +70°C (MC3302) T_{low} = -40°C, T_{high} = +85°C (LM2901) T_{low} = -40°C, T_{high} = +105° (LM2901V & NCV2901) T_{low} = -40°C, T_{high} = +125°C NCV2901 is qualified for automotive use.

- 4. At the output switch point, V_O ≈ 1.4 Vdc, R_S ≤ 100 Ω 5.0 Vdc ≤ V_{CC} ≤ 30 Vdc, with the inputs over the full common mode range (0 Vdc to V_{CC} = 1.5 Vdc)
- (0 Vdc to V_{CC} –1.5 Vdc).

 5. The bias current flows out of the inputs due to the PNP input stage. This current is virtually constant, independent of the output state.
- 6. The response time specified is for a 100 mV input step with 5.0 mV overdrive. For larger signals, 300 ns is typical.

PERFORMANCE CHARACTERISTICS ($V_{CC} = +5.0 \text{ Vdc}$, $T_A = T_{low} \text{ to } T_{high} \text{ [Note 7]}$)

		LI	M239/3	39		901/29 ICV290		1	MC3302	2	
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage (Note 8)	V _{IO}	-	-	±9.0	_	_	±15	_	-	±40	mVdc
Input Bias Current (Notes 8, 9)	I _{IB}	-	-	400	_	-	500	-	-	1000	nA
(Output in Analog Range)											
Input Offset Current (Note 8)	I _{IO}	-	-	±150	_	-	±200	-	-	±300	nA
Input Common Mode Voltage Range	V _{ICMR}	0	-	V _{CC} -2.0	0	-	V _{CC} -2.0	0	_	V _{CC} -2.0	٧
Saturation Voltage	V _{sat}	-	-	700	-	-	700	-	-	700	mV
$V_I(-) \ge +1.0 \text{ Vdc}, V_I(+) = 0,$ $I_{sink} \le 4.0 \text{ mA}$											
Output Leakage Current	l _{OL}	-	-	1.0	_	-	1.0	-	-	1.0	μΑ
$V_{I}(+) \ge +1.0 \text{ Vdc}, V_{I}(-) = 0,$ $V_{O} = 30 \text{ Vdc}$											
Differential Input Voltage	V _{ID}	-	-	V _{CC}	_	-	V _{CC}	_	-	V _{CC}	Vdc
All $V_l \ge 0 \text{ Vdc}$											

- (LM239) T_{low} = -25°C, T_{high} = +85° (LM339) T_{low} = 0°C, T_{high} = +70°C (MC3302) T_{low} = -40°C, T_{high} = +85°C (LM2901) T_{low} = -40°C, T_{high} = +105° (LM2901V & NCV2901) T_{low} = -40°C, T_{high} = +125°C NCV2901 is qualified for automotive use.
- 8. At the output switch point, $V_O \approx 1.4$ Vdc, $R_S \le 100~\Omega$ 5.0 Vdc $\le V_{CC} \le 30$ Vdc, with the inputs over the full common mode range (0 Vdc to V_{CC} –1.5 Vdc).

 9. The bias current flows out of the inputs due to the PNP input stage. This current is virtually constant, independent of the output state.
- 10. The response time specified is for a 100 mV input step with 5.0 mV overdrive. For larger signals, 300 ns is typical.

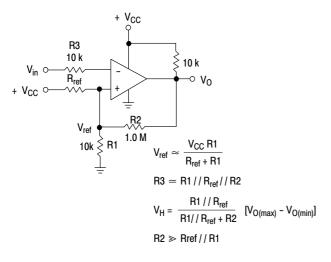


Figure 2. Inverting Comparator with Hysteresis

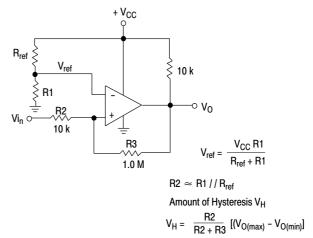
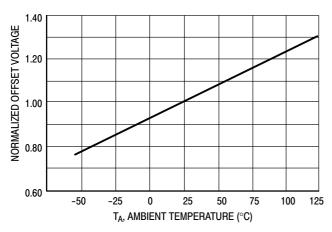


Figure 3. Noninverting Comparator with Hysteresis

Typical Characteristics

 $(V_{CC} = 15 \text{ Vdc}, T_A = +25^{\circ}\text{C} \text{ (each comparator) unless otherwise noted.)}$



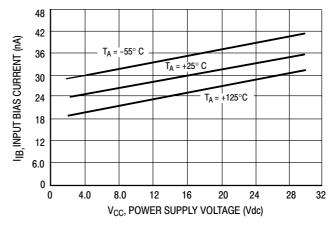


Figure 4. Normalized Input Offset Voltage

Figure 5. Input Bias Current

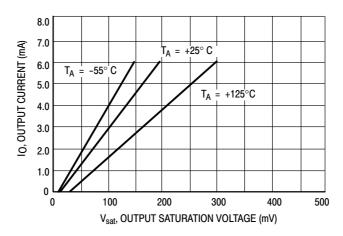
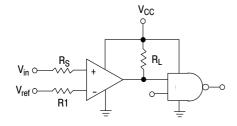


Figure 6. Output Sink Current versus Output Saturation Voltage



 R_S = Source Resistance $R1 \simeq R_S$

Logic	Device	V _{CC} (V)	R _L kΩ
CMOS	1/4 MC14001	+15	100
TTL	1/4 MC7400	+5.0	10

Figure 7. Driving Logic

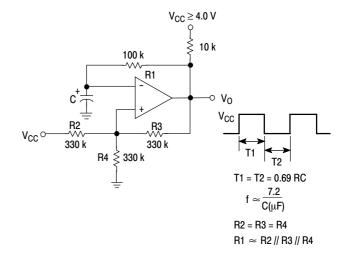


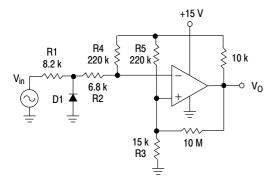
Figure 8. Squarewave Oscillator

APPLICATIONS INFORMATION

These quad comparators feature high gain, wide bandwidth characteristics. This gives the device oscillation tendencies if the outputs are capacitively coupled to the inputs via stray capacitance. This oscillation manifests itself during output transitions (V_{OL} to V_{OH}). To alleviate this situation input resistors < 10 k Ω should be used. The

addition of positive feedback (< 10 mV) is also recommended. It is good design practice to ground all unused input pins.

Differential input voltages may be larger than supply voltages without damaging the comparator's inputs. Voltages more negative than -300 mV should not be used.

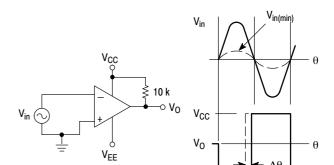


D1 prevents input from going negative by more than $\,$ 0.6 V.

$$R1 + R2 = R3$$

 $R3 \le \frac{R5}{10}$ for small error in zero crossing

Figure 9. Zero Crossing Detector (Single Supply)



 $V_{in(min)} \approx 0.4 \text{ V}$ peak for 1% phase distortion ($\Delta\theta$).

Figure 10. Zero Crossing Detector (Split Supplies)

 V_{EE}

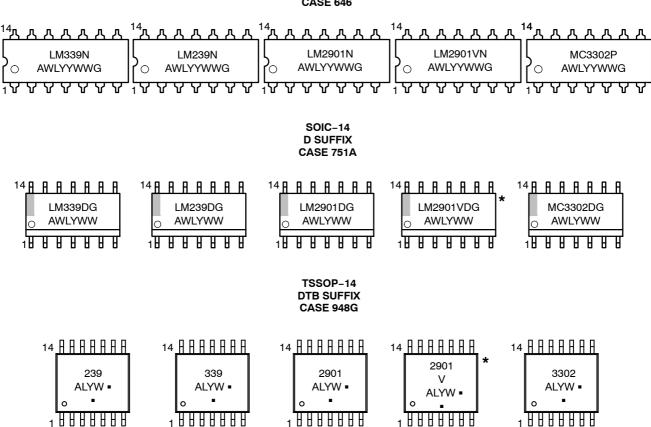
ORDERING INFORMATION

Device	Package	Shipping [†]
LM239DG	SOIC-14	55 Units/Tube
LM239DR2G	SOIC-14	0500 / Tara & Basi
LM239DTBR2G	TSSOP-14	2500 / Tape & Reel
LM239NG	PDIP-14	25 Units/Rail
LM339DG	SOIC-14	55 Units/Tube
LM339DR2G	SOIC-14	0500 /T 0 D 1
LM339DTBR2G	TSSOP-14	2500 / Tape & Reel
LM339NG	PDIP-14	25 Units/Rail
LM2901DG	SOIC-14	55 Units/Rail
LM2901DR2G	SOIC-14	0500 /T 0 D 1
LM2901DTBR2G	TSSOP-14	2500 / Tape & Reel
LM2901NG	PDIP-14	25 Units/Rail
LM2901VDG	SOIC-14	55 Units/Tube
LM2901VDR2G	SOIC-14	0500 /T 0 D 1
LM2901VDTBR2G	TSSOP-14	2500 / Tape & Reel
LM2901VNG	PDIP-14	25 Units/Rail
NCV2901DR2G	SOIC-14	0500 /T 0 D 1
NCV2901DTBR2G	TSSOP-14	2500 / Tape & Reel
NCV2901CTR	Bare Die	6000 / Tape & Reel
MC3302DG	SOIC-14	55 Units/Tube
MC3302DR2G	SOIC-14	0500 / Table 0 Paul
MC3302DTBR2G	TSSOP-14	2500 / Tape & Reel
MC3302PG	PDIP-14	25 Units/Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS

PDIP-14 N, P SUFFIX CASE 646



A = Assembly Location

WL, L = Wafer Lot YY, Y = Year

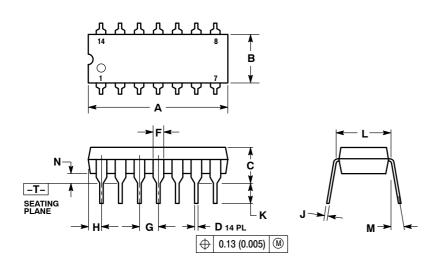
WW, W = Work Week

G or ■ = Pb-Free Package

(Note: Microdot may be in either location)
*This marking diagram also applies to NCV2901.

PACKAGE DIMENSIONS

PDIP-14 CASE 646-06 ISSUE P



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. DIMENSION I TO CENTER OF LEADS WHEN FORMED PARALLEL.

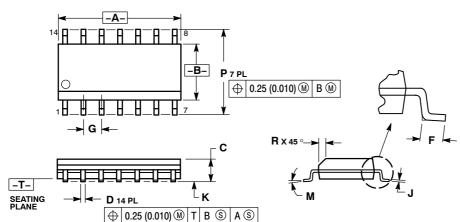
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIM	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	19.56	
В	0.240	0.260	6.10	6.60	
С	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100	BSC	2.54 BSC		
Н	0.052	0.095	1.32	2.41	
J	0.008	0.015	0.20	0.38	
K	0.115	0.135	2.92	3.43	
L	0.290	0.310	7.37	7.87	
М		10 °		10 °	
N	0.015	0.039	0.38	1.01	

PACKAGE DIMENSIONS

SOIC-14 CASE 751A-03 **ISSUE H**

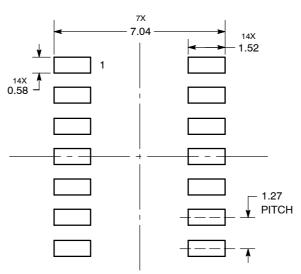


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE
 DAMBAR PROTRUSION. ALLOWABLE
 DAMBAR PROTRUSION SHALL BE 0.127
 (0.005) TOTAL IN EXCESS OF THE D
 DIMENSION AT MAXIMUM MATERIAL
 CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	8.55	8.75	0.337	0.344
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
J	0.19	0.25	0.008	0.009
Κ	0.10	0.25	0.004	0.009
М	0 °	7°	0 °	7°
Р	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

SOLDERING FOOTPRINT*

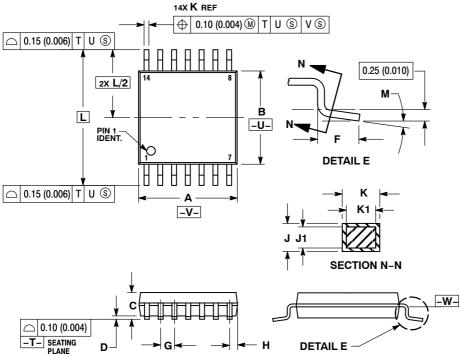


DIMENSIONS: MILLIMETERS

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TSSOP-14 CASE 948G-01 **ISSUE B**



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

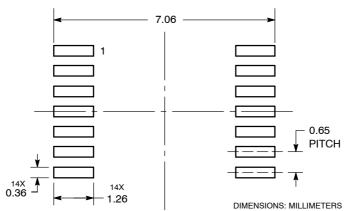
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. MAXIMUM MATERIAL CONDITION.
 6. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE
 DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.90	5.10	0.193	0.200	
В	4.30	4.50	0.169	0.177	
С	-	1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026 BSC		
Н	0.50	0.60	0.020	0.024	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40	BSC	0.252	BSC	
М	0 °	8 °	0°	8 °	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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